



Vishay Semiconductors

# **Small Signal Switching Diodes, High Voltage**



## **DESIGN SUPPORT TOOLS**

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#### **MECHANICAL DATA**

Case: SOD-123

Weight: approx. 10.3 mg
Packaging codes / options:

18/10K per 13" reel (8 mm tape), 10K/box 08/3K per 7" reel (8 m tape), 15K/box

#### **FEATURES**

- Silicon epitaxial planar diodes
- For general purpose
- AEC-Q101 qualified available
- Base P/N-E3 RoHS-compliant, commercial grade





- Base P/N-HE3 RoHS-compliant, AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

| PARTS TABLE |                         |  |                 |                       |               |  |
|-------------|-------------------------|--|-----------------|-----------------------|---------------|--|
| PART        | TYPE<br>DIFFERENTIATION | ORDERING CODE  | TYPE<br>MARKING | CIRCUIT CONFIGURATION | REMARKS       |  |
| BAV19W      | V <sub>R</sub> = 100 V  | BAV19W-E3-08 or BAV19W-E3-18<br>BAV19W-HE3-08 or BAV19W-HE3-18 | A8              | Single                | Tape and reel |  |
| BAV20W      | V <sub>R</sub> = 150 V  | BAV20W-E3-08 or BAV20W-E3-18<br>BAV20W-HE3-08 or BAV20W-HE3-18 | A9              | Single                | Tape and reel |  |
| BAV21W      | V <sub>R</sub> = 200 V  | BAV21W-E3-08 or BAV21W-E3-18<br>BAV21W-HE3-08 or BAV21W-HE3-18 | AA              | Single                | Tape and reel |  |

| <b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |                                 |        |                    |       |      |  |
|--|---------------------------------|--------|--------------------|-------|------|--|
| PARAMETER  | TEST CONDITION                  | PART   | SYMBOL             | VALUE | UNIT |  |
|  |                                 | BAV19W | $V_R$              | 100   | V    |  |
| Continuous reverse voltage   |                                 | BAV20W | $V_R$              | 150   | V    |  |
|  |                                 | BAV21W | $V_R$              | 200   | V    |  |
|  |                                 | BAV19W | $V_{RRM}$          | 120   | V    |  |
| Repetitive peak reverse voltage  |                                 | BAV20W | $V_{RRM}$          | 200   | V    |  |
|  |                                 | BAV21W | $V_{RRM}$          | 250   | V    |  |
| DC Forward current (1)   |                                 |        | I <sub>F</sub>     | 250   | mA   |  |
| Rectified current (average) half wave rectification with resist. load (1)              |                                 |        | I <sub>F(AV)</sub> | 200   | mA   |  |
| Repetitive peak forward current (1)  | f ≥ 50 Hz, θ = 180°             |        | I <sub>FRM</sub>   | 625   | mA   |  |
| Surge forward current  | t < 1 s, T <sub>j</sub> = 25 °C |        | I <sub>FSM</sub>   | 1     | А    |  |
| Power dissipation (1)  | •                               |        | P <sub>tot</sub>   | 410   | mW   |  |



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| THERMAL CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified) |                |                   |             |      |  |  |
|--|----------------|-------------------|-------------|------|--|--|
| PARAMETER  | TEST CONDITION | SYMBOL            | VALUE       | UNIT |  |  |
| Thermal resistance junction to ambient air (1)                                 |                | R <sub>thJA</sub> | 375         | °C/W |  |  |
| Junction temperature (1)   |                | Tj                | 150         | °C   |  |  |
| Storage temperature range (1)  |                | T <sub>stg</sub>  | -65 to +150 | °C   |  |  |
| Operating temperature range  |                | T <sub>op</sub>   | -55 to +150 | °C   |  |  |

#### Note

<sup>(1)</sup> Valid provided that leads are kept at ambient temperature

| <b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |   |        |                 |      |      |      |      |
|--|---|--------|-----------------|------|------|------|------|
| PARAMETER  | TEST CONDITION  | PART   | SYMBOL          | MIN. | TYP. | MAX. | UNIT |
| Commond voltogo  | I <sub>F</sub> = 100 mA   |        | V <sub>F</sub>  |      |      | 1    | V    |
| Forward voltage  | I <sub>F</sub> = 200 mA   |        | V <sub>F</sub>  |      |      | 1.25 | V    |
|  | V <sub>R</sub> = 100 V  | BAV19W | I <sub>R</sub>  |      |      | 100  | nA   |
|  | V <sub>R</sub> = 100 V, T <sub>j</sub> = 100 °C                                     | BAV19W | I <sub>R</sub>  |      |      | 15   | μA   |
| Lackaga ayyyant  | V <sub>R</sub> = 150 V  | BAV20W | I <sub>R</sub>  |      |      | 100  | nA   |
| Leakage current  | V <sub>R</sub> = 150 V, T <sub>j</sub> = 100 °C                                     | BAV20W | I <sub>R</sub>  |      |      | 15   | μA   |
|  | V <sub>R</sub> = 200 V  | BAV21W | I <sub>R</sub>  |      |      | 100  | nA   |
|  | V <sub>R</sub> = 200 V, T <sub>j</sub> = 100 °C                                     | BAV21W | I <sub>R</sub>  |      |      | 15   | μΑ   |
| Dynamic forward resistance   | I <sub>F</sub> = 10 mA  |        | r <sub>f</sub>  |      | 5    |      | Ω    |
| Diode capacitance  | V <sub>R</sub> = 0, f = 1 MHz   |        | C <sub>D</sub>  |      | 1.5  |      | pF   |
| Reverse recovery time  | $I_F = 30 \text{ mA}, I_R = 30 \text{ mA}, \\ i_R = 3 \text{ mA}, R_L = 100 \Omega$ |        | t <sub>rr</sub> |      |      | 50   | ns   |

## **TYPICAL CHARACTERISTICS** ( $T_{amb} = 25$ °C, unless otherwise specified)

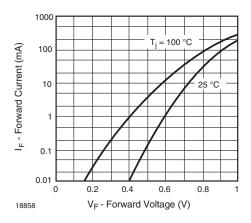


Fig. 1 - Forward Current vs. Forward Voltage

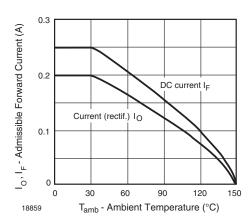


Fig. 2 - Admissible Forward Current vs. Ambient Temperature

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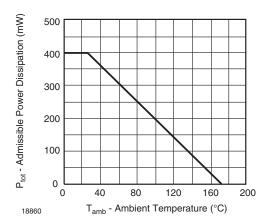


Fig. 3 - Admissible Power Dissipation vs. Ambient Temperature

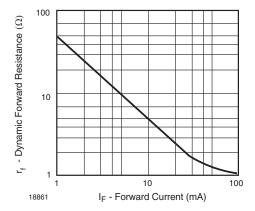


Fig. 4 - Dynamic Forward Resistance vs. Forward Current

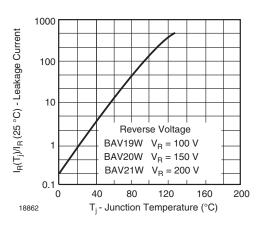


Fig. 5 - Leakage Current vs. Junction Temperature

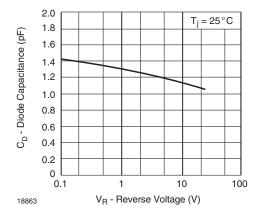


Fig. 6 - Capacitance vs. Reverse Voltage

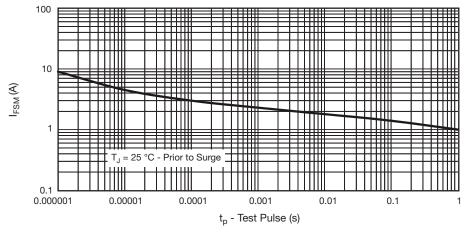


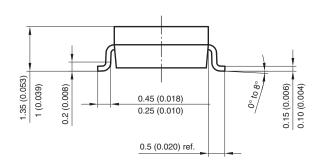
Fig. 7 - Non-Repetitive Peak Forward Current vs. Pulse Duration Maximum Admissible Values of Square Pulse

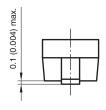


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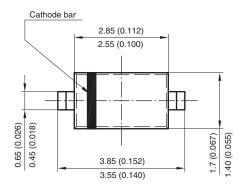
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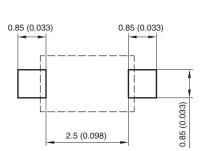
### PACKAGE DIMENSIONS in millimeters (inches): SOD-123





Mounting Pad Layout





Rev. 4 - Date: 24. Sep. 2009 Document no.: S8-V-3910.01-001 (4)



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